**TOSHIBA TA2018FN** 

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

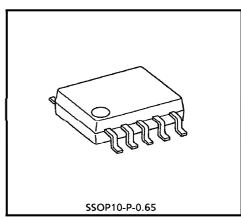
# TA2018FN

# DC/DC CONVERTER FOR ELECTRIC TUNING (1.5V USE)

The TA2018FN is a DC/DC converter IC which is developed for biasing variable capacitance diodes of tuner system. It is especially suitable for supplying high voltage (about 14.3V) for digital tuning (FM/TV/AM) system at low power operation.

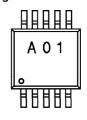
#### **FEATURES**

- Few external parts.
- Excellent spurious radiation by oscillation of sine wave.
- Output voltage :  $V_O = 14.3V$  (Typ.)
- Excellent regulatory capability of output voltage against fluctuation of supply voltage, and of ambient temperature.
- Built-in constant current source, it is suitable for digital tuning system. (ICTL can be controlled by RCTL)
- Built-in power switch.
- Low supply current (V<sub>CC</sub> = 1.2V, Ta = 25°C, I<sub>O</sub> = 30 $\mu$ A)  $I_{CC} = 2.1 \text{mA} \text{ (Typ.)}$
- Operating supply voltage range (Ta = 25°C)  $V_{CC}(opr) = 0.9 \sim 4V$

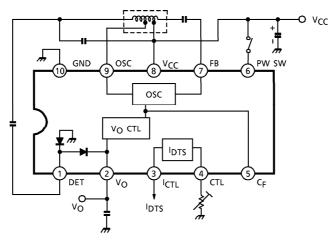


Weight: 0.04g (Typ.)

#### Marking



#### **BLOCK DIAGRAM**



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## **TERMINAL EXPLANATION**

Terminal voltage : Typical terminal voltage with test circuit ( $V_{CC} = 1.2V$ ,  $Ta = 25^{\circ}C$ )

TERMINAL		FUNCTION	INTERNAL CIRCUIT	TERMINAL
No.	NAME	TONCTION	INTERNAL CIRCOTT	VOLTAGE (V)
1	DET	Boosted output	-W	_
2	νo	(Voltage double rectifier)		14.3
5	C <sub>F</sub>	Don't connect any external parts with this terminal	DC FEED \$ 1kΩ BACK	0.4
3	ICTL	Constant current source     Vo supplies this circuit with power	6kΩ T	_
4	CTL	source. (for digital tuning)	2 4 3 IDTS	_
6	PW SW	Power on / off switch     VCC : Power on     Open / GND : Power off	ν <sub>CC</sub> - 6 - 8κΩ - γ <sub>CC</sub> - 6 - 8κΩ - 7 - 8	_
7	FB	Hartley type oscillator	V <sub>CC</sub>	0.7
8	V <sub>CC</sub>	$f_{OSC} = \frac{1}{2\pi\sqrt{L_3 \cdot C_1}}$ • Controlling oscillation current at the		1.2
9	osc	terminal of FB	-K-\$\frac{3}{2}\frac{1}{2}	_
10	GND	_	_	0

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#### **APPLICATION NOTE**

#### 1. PW SW

It is necessary to connect an external pull-down resistor with the terminal PW SW (pin 6), in case that this IC is turned on due to external noise etc.

#### 2. Designing of coil

This IC has the output voltage by means of boosting the oscillation voltage, derived from Hartley type oscillator circuit and of voltage-double rectifier with  $C_3$ ,  $D_1$  and  $D_2$ .

(1) Designing of oscillation frequency

$$f_{osc} = \frac{1}{2\pi\sqrt{L_3 \cdot C_2}}$$

(2) Coil turns can be designed as following:

$$V_{osc(p-p)} = 2(V_{CC(min)} - V_{CE1(sat)})$$

$$n = \frac{n3}{n2} = \frac{V_O}{V_{OSC(p-p)}}$$

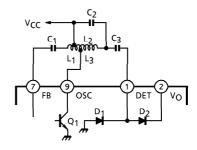


Fig.1 Oscillator and Voltage-Double

(Note) V<sub>CC (min)</sub> : minimum of supply voltage designed by a equipment

 $V_{CE1\,(sat)}$  : saturation voltage of  $Q_1$  n : coil turns ratio ( $L_2$ ,  $L_3$ )  $V_O$  : output voltage ( $V_O \rightleftharpoons 14.3V$ )

The turn of  $L_1$  is designed, so as to make the terminal of FB be about  $200\sim300\text{mVp-p}$  through  $C_1$ . The turn of  $L_1$  should be small, and the capacitance of  $C_1$  and  $Q_0$  of coil should be large, for the oscillation start at turning power on.

(3) Allowance is advisable for coil design of n,  $Q_0$ . However, spurious radiation can be reduced, in case that the output current and n of coil don't make large.

#### 3. Pattern diagram

The Fig.2 shows the oscillation loop. This pattern diagram should be small, because spurious radiation due to the oscillation is reduced.

The Fig.3 shows the rectifier loop. This pattern diagram should be the small, because spurious radiation due to the switching rectifier is reduced. The two loops should be isolated from other DC lines.

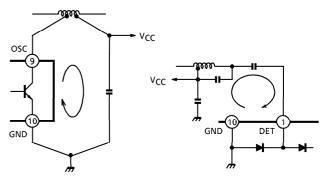


Fig.2 Oscillation Loop Fig.3 Rectifier Loop

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### 4. Output current

Total output current (IO and ICTL) should not be smaller than  $30\mu\text{A}$ , because this IC start blocking oscillation etc. Note that this condition will change according to coil setting etc.

#### 5. Terminal CF

Any external parts should not be connected with this terminal, because this IC doesn't operate normally.

# 6. ICTL

 $I_{CTL}$  can be controlled by  $R_{CTL}$  resistor between pin 4 and GND, note that  $I_{CTL}$  should be set to  $180\,\mu\text{A}$  or smaller (see Fig.4).

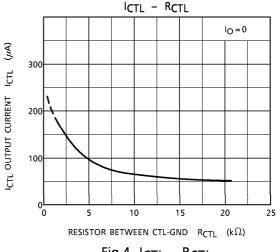


Fig.4 I<sub>CTL</sub> - R<sub>CTL</sub>

# MAXIMUM RATINGS (Ta = 25C°)

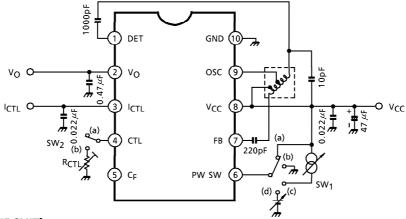
CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	V <sub>C</sub> C	4.5	V	
Output voltage	٧o	18	\ \ \	
Constant Current Source	<sup>I</sup> CTL	5	mA	
Circuit Output Current	D-	200		
Power Dissipation (Note)	PD	300	mW	
Operating Temperature	T <sub>opr</sub>	<b>- 25∼75</b>	∘ر ا	
Storage Temperature	T <sub>stg</sub>	<b>- 55∼150</b>		

(Note) Derated above  $Ta = 25^{\circ}C$  in the proportion of 2.4mW.

ELECTRICAL CHARACTERISTICS Unless otherwise specified :  $V_{CC}$  = 1.2V,  $T_{a}$  = 25°C,  $f_{osc}$  = 3MHz,  $I_{O}$  = 30 $\mu$ A,  $SW_{1}$  : a,  $SW_{2}$  : a

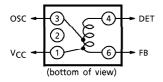
CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	<sup>I</sup> CC1	_	PW OFF, SW <sub>1</sub> : b	_	_	5	$\mu$ A
Supply Current	lcc2	_		_	2.1	3	mA
Boosted Output Voltage	٧o	_		13.5	14.3	15.1	V
VO Supply Voltage Fluctuation	ΔVO	_	V <sub>CC</sub> = 4V→0.9V	- 20	0	+ 20	mV
V <sub>O</sub> Maximum Output Current	<sup>I</sup> O (MAX)	_	$\Delta V_O = 50$ mV, with respect to standard, $I_{CTL} = 30 \mu A$	180	300	_	μΑ
VO Ambient Temperature Coefficient	V <sub>O</sub> /T	_		_	+ 1.2	_	mV/°C
Constant Current Source	lo-r		$I_{\Omega} = 0$ , SW <sub>2</sub> : b (R <sub>CTL</sub> = 4.7k $\Omega$ )	80	100	120	
Output Current	<sup>I</sup> CTL		10 = 0, 3445 : p (UC [=4:7K22)	80	100	120	$\mu$ A
I <sub>CTL</sub> Maximum Current	ICTL (MAX)	_	$I_O = 0$ , $SW_2$ : b, (adjust $R_{CTL}$ ) $\Delta V_O = 50$ mV, with respect to standard, $I_{CTL} = 30 \mu A$	_	270	_	μΑ
Power Switch On Current	16	_	$V_{CC} = 0.9V, V_O \ge 13V, SW_1 : c$	5	_	_	μΑ
Power Switch Off Voltage	٧6	_	$V_{CC} = 0.9V, V_O \le 3.5V, SW_1 : d$	0	_	0.3	V

#### **TEST CIRCUIT**



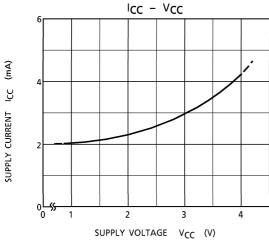
# **COIL DATA (TEST CIRCUIT)**

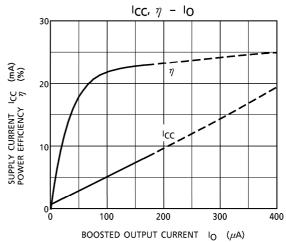
TEST	L (μH) Q 4-6		TURN			WIRE	REFERENCE
FREQUENCY			6-1	1-3	3-4	$(mm\phi)$	REFERENCE
796kHz	152 25 $2\frac{1}{2}$	2 1	0 89	89	0.04UEW	SUMIDA ELECTRIC & Co.,Ltd.	
/90KHZ		٥	2	0.040EW	5201-018		

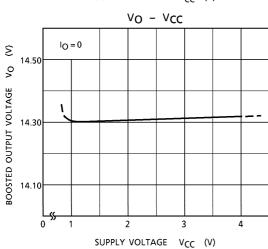


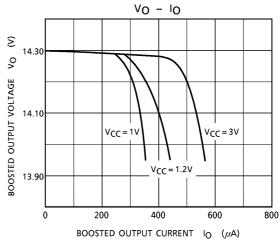
#### **CHARACTERISTIC CURVES**

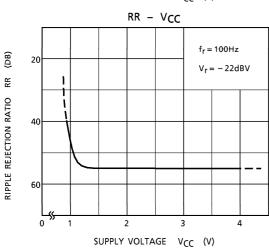
Unless otherwise specified :  $V_{CC} = 1.2V$ ,  $I_{O} = 30 \mu A$ ,  $T_{O} = 25 ^{\circ} C$ ,  $f_{OSC} = 3 MHz$ 

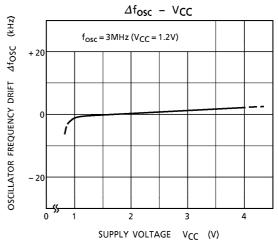


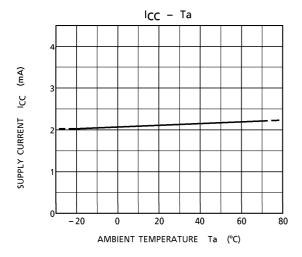


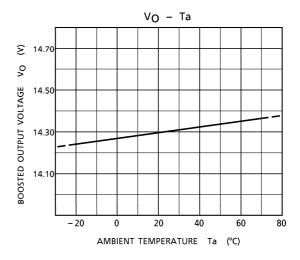


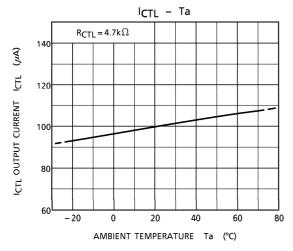


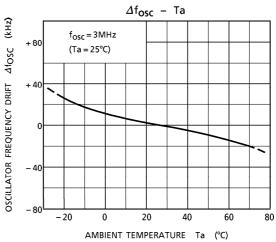






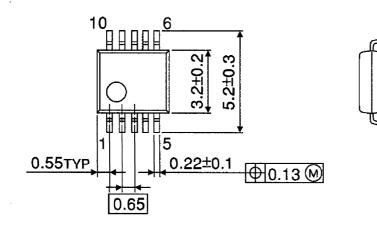


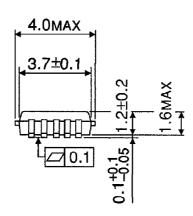


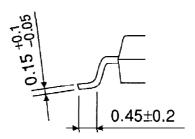


#### OUTLINE DRAWING SSOP10-P-0.65

Unit: mm







Weight: 0.04g (Typ.)